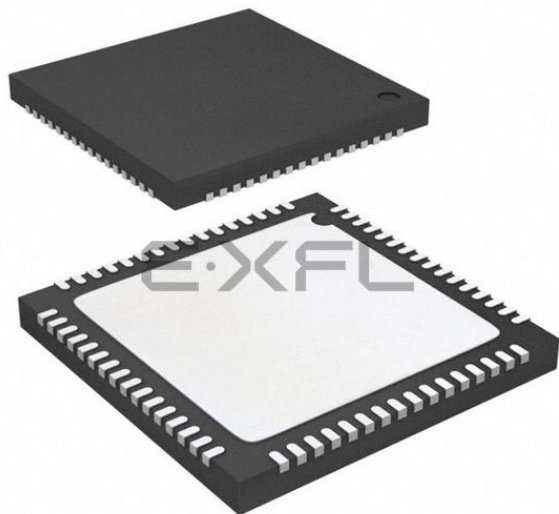




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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M3
Core Size	32-Bit Single-Core
Speed	26MHz
Connectivity	I ² C, SPI, UART/USART
Peripherals	DMA, POR, PWM, WDT
Number of I/O	44
Program Memory Size	256KB (256K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	96K x 8
Voltage - Supply (Vcc/Vdd)	1.74V ~ 3.6V
Data Converters	A/D 8x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-WFQFN Exposed Pad, CSP
Supplier Device Package	64-LFCSP-WQ (9x9)
Purchase URL	https://www.e-xfl.com/product-detail/analog-devices/aducm3029bcpz-rl

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REVISION HISTORY

3/2017—Revision 0: Initial Version

ADuCM3027/ADuCM3029

- Configurable for ultralow power operation
 - Deep sleep mode, dynamic power management
 - Programmable clock generator unit

ARM Cortex-M3 Memory Subsystem

The memory map of the [ADuCM3027/ADuCM3029](#) is based on the Cortex-M3 model from ARM. By retaining the standardized memory mapping, it is easier to port applications across M3 platforms.

The [ADuCM3027/ADuCM3029](#) application development is based on memory blocks across code/SRAM regions. Internal memory is available via internal SRAM and internal flash.

Code Region

Accesses in this region (0x0000 0000 to 0x0001 FC00 for the [ADuCM3027](#) and 0x0000 0000 to 0x0003 FFFF for the [ADuCM3029](#)) are performed by the core and target the memory and cache resources.

SRAM Region

Accesses in this region (0x2000 0000 to 0x2004 7FFF) are performed by the ARM Cortex-M3 core. The SRAM region of the core can otherwise act as a data region for an application.

- **Internal SRAM Data Region.** This space can contain read/write data. Internal SRAM can be partitioned between code and data (SRAM region in M3 space) in 32 KB blocks. Access to this region occurs at core clock speed with no wait states. It also supports read/write access by the Cortex-M3 core and read/write DMA access by system devices. It supports exclusive memory accesses via the global exclusive access monitor within the Cortex-M3 platform.
- **System MMRs.** Various system memory mapped registers (MMRs) reside in this region.

System Region

Accesses in this region (0xE000 0000 to 0xF7FF FFFF) are performed by the ARM Cortex-M3 core and are handled within the Cortex-M3 platform.

- **CoreSight™ ROM.** The read only memory (ROM) table entries point to the debug components of the processor.
- **ARM APB Peripheral.** This space is defined by ARM and occupies the bottom 256 KB/128 KB of the system (SYS) region (0xE000 0000 to 0xE004 0000) depending on the device used. The space supports read/write access by the M3 core to the internal peripherals of the ARM core (NVIC, system control space (SCS), wake-up interrupt controller (WIC)) and CoreSight ROM. It is not accessible by system DMA.

MEMORY ARCHITECTURE

The internal memory of the [ADuCM3027/ADuCM3029](#) is shown in [Figure 2](#). It incorporates up to 256 KB of embedded flash memory for program code and nonvolatile data storage, 32 KB of data SRAM, and 32 KB of SRAM (configured as instruction space or data space).

SRAM Region

This memory space contains the application instructions and literal (constant) data that must be accessed in real-time. It supports read/write access by the ARM Cortex-M3 core and read/write DMA access by system peripherals. Byte, half-word, and word accesses are supported.

SRAM is divided into 32 KB data SRAM and 32 KB instruction SRAM. If instruction SRAM is not enabled, then the associated 32 KB can be mapped as data SRAM, resulting in 64 KB of data SRAM.

Parity bit error detection (optional) is available on all SRAM memories. Two parity bits are associated with each 32-bit word.

When the cache controller is enabled, 4 KB of the instruction SRAM is reserved as cache memory.

Users can select the SRAM configuration modes depending on the instruction SRAM and cache needed.

In hibernate mode, 8 KB to 32 KB of the SRAM can be retained in increments of 8 KB. 8 KB of data SRAM is always retained. Users can additionally retain

- 16 KB out of 32 KB of instruction SRAM
- 8 KB out of 32 KB of data SRAM

MMRs (Peripheral Control and Status)

For the address space containing MMRs, refer to [Figure 2](#).

These registers provide control and status for on-chip peripherals of the [ADuCM3027/ADuCM3029](#). For more information about the MMRs, refer to the [ADuCM302x Ultra Low Power ARM Cortex-M3 MCU with Integrated Power Management Hardware Reference](#).

Flash Memory

The [ADuCM3027/ADuCM3029](#) MCUs include 128 KB to 256 KB of embedded flash memory, which is accessed using a flash controller. For memory available on each product, see [Table 1](#). The flash controller is coupled with a cache controller. A prefetch mechanism is implemented in the flash controller to optimize code performance.

Flash writes are supported by a key hole mechanism via advanced peripheral bus (APB) writes to MMRs. The flash controller provides support for DMA-based key hole writes.

With respect to flash integrity, the devices support the following:

- A fixed user key required for running protected commands, including mass erase and page erase.
- An optional and user definable user failure analysis key (FAA key). Analog Devices personnel need this key while performing failure analysis.
- An optional and user definable write protection for user accessible memory.
- An optional 8-bit ECC. It is enabled by default. It is recommended not to disable ECC.

The key differences between RTC0 and RTC1 (FLEX_RTC) are shown in [Table 3](#).

Table 3. RTC Features

Features	RTC0	RTC1 (FLEX_RTC)
Resolution of Time Base (Prescaling)	Counts time at 1 Hz in units of seconds. Operationally, always prescales to 1 Hz (for example, divide by 32,768) and always counts real time in units of seconds.	Can prescale the clock by any power of two from 0 to 15. It can count time in units of any of these 16 possible prescale settings. For example, the clock can be prescaled by 1, 2, 4, 8, ..., 16384, or 32768.
Source Clock	LFXTAL.	Depending on the low frequency multiplexer (LFMUX) configuration, the RTC is clocked by the LFXTAL or the LFOSC.
Wake-Up Timer	Wake-up time is specified in units of seconds.	Supports alarm times down to a resolution of 30.7 μ s, that is, where the time is specified down to a specific 32 kHz clock cycle.
Number of Alarms	One alarm only. Uses an absolute, nonrepeating alarm time, specified in units of 1 sec.	Two alarms. One absolute alarm time and one periodic alarm, repeating every 60 prescaled time units.
SensorStrobe Mechanism	Not available.	SensorStrobe is an alarm mechanism in the RTC that causes an output pulse to be sent via GPIOs to an external device to instruct the device to take a measurement or perform some action at a specific time. SensorStrobe events are scheduled at a specific target time relative to the real-time count of the RTC. SensorStrobe can be enabled in active, Flexi, and hibernate modes.
Input Capture	Not available.	Input capture takes a snapshot of the RTC when an external device signals an event via a transition on one of the GPIO inputs to the ADuCM3027/ADuCM3029 . Typically, an input-capture event is triggered by an autonomous measurement or action on such a device, which then signals to the ADuCM3027/ADuCM3029 that the RTC must take a snapshot of time corresponding to the event. Taking the snapshot can wake up the ADuCM3027/ADuCM3029 and cause an interrupt to the CPU. The CPU can subsequently obtain information from the RTC on the exact 32 kHz cycle on which the input capture event occurred.

Hardware

The [ADuCM3029 EZ-KIT](#)[®] is available to prototype sensor configurations with the [ADuCM3027/ADuCM3029](#) MCUs.

Software

The [ADuCM3029 EZ-KIT](#) includes a complete development and debug environment for the [ADuCM3027/ADuCM3029](#) MCUs. The board support package (BSP) for the [ADuCM3027/ADuCM3029](#) is provided for the IAR Embedded Workbench for ARM, Keil[™], and CrossCore[®] embedded studio (CCES) environments.

The BSP also includes operating system (OS) aware drivers and example code for all the peripherals on the devices.

ADDITIONAL INFORMATION

The following publications that describe the [ADuCM3027/ADuCM3029](#) MCUs can be ordered from any Analog Devices sales office or accessed electronically on the Analog Devices website:

- [ADuCM302x Ultra Low Power ARM Cortex-M3 MCU with Integrated Power Management Hardware Reference.](#)
- [ADuCM3027/ADuCM3029 Anomaly List](#)

This data sheet describes the ARM Cortex-M3 core and memory architecture used on the [ADuCM3027/ADuCM3029](#) MCUs, but does not provide detailed programming information for the ARM processor. For more information about programming the ARM processor, visit the ARM Infocenter web page.

The applicable documentation for programming the ARM Cortex-M3 processor include the following:

- *ARM Cortex-M3 Devices Generic User Guide*
- *ARM Cortex-M3 Technical Reference Manual*

REFERENCE DESIGNS

The [Circuits from the Lab](#)[®] page provides the following:

- Graphical circuit block diagram presentation of signal chains for a variety of circuit types and applications
- Drill down links for components in each chain to selection guides and application information
- Reference designs applying best practice design techniques

SECURITY FEATURES DISCLAIMER

To our knowledge, the Security Features, when used in accordance with the data sheet and hardware reference manual specifications, provide a secure method of implementing code and data safeguards. However, Analog Devices does not guarantee that this technology provides absolute security.

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Power Supply Current

Table 4, Table 5, and Table 6 describe power supply current for V_{BAT} .

Table 4. Active Mode—Current Consumption When $V_{BAT} = 3.0\text{ V}$

Conditions	Buck	Typ ¹	Max ²	Unit
Code ³ executing from flash, cache enabled, peripheral clocks off, HCLK = 6.5 MHz	Enabled	0.40		mA
Code ³ executing from flash, cache enabled, peripheral clocks off, HCLK = 26 MHz	Enabled	0.98	1.29	mA
	Disabled	1.75	2.38	mA
Code ³ executing from flash, cache disabled, peripheral clocks off, HCLK = 26 MHz	Enabled	1.28	1.64	mA
	Disabled	2.34	3.0	mA
Code ³ executing from SRAM, peripheral clocks off, HCLK = 26 MHz	Enabled	0.95	1.36	mA
	Disabled	1.78	2.48	mA
Code ³ executing from flash, cache enabled, peripheral clocks on, HCLK = 26 MHz, PCLK = 26 MHz	Enabled	1.08	1.43	mA
	Disabled	1.99	2.67	mA
Code ³ executing from flash, cache disabled, peripheral clocks on, HCLK = 26 MHz, PCLK = 26 MHz	Enabled	1.37	1.78	mA
	Disabled	2.55	3.29	mA
Code ³ executing from SRAM, peripheral clocks on, HCLK = 26 MHz, PCLK = 26 MHz	Enabled	1.08	1.49	mA
	Disabled	2.03	2.74	mA

¹ $T_J = 25^\circ\text{C}$.

² $T_J = 85^\circ\text{C}$.

³ The code being executed is a prime number generation in a continuous loop, with HFOSC as the system clock source.

Table 5. Flexi™ Mode—Current Consumption When $V_{BAT} = 3.0\text{ V}$

Conditions	Buck	Typ ¹	Max ²	Unit
Peripheral clocks off	Enabled	0.3	0.67	mA
	Disabled	0.52	1.11	mA
Peripheral clocks on, PCLK = 26 MHz	Enabled	0.39	0.80	mA
	Disabled	0.7	1.38	mA

¹ $T_J = 25^\circ\text{C}$.

² $T_J = 85^\circ\text{C}$.

Table 6. Deep Sleep Modes¹—Current Consumption When $V_{BAT} = 3.0\text{ V}$

Mode	Conditions	−40°C Typ	+25°C Typ	+85°C Typ	+85°C Max	Unit
Hibernate	RTC1 and RTC0 disabled, 8 KB SRAM retained, LFXTAL off	0.66	0.75	2.0	6.05	μA
	RTC1 and RTC0 disabled, 16 KB SRAM retained, LFXTAL off	0.67	0.77	2.4	6.4	μA
	RTC1 and RTC0 disabled, 24 KB SRAM retained, LFXTAL off	0.68	0.79	2.6	6.75	μA
	RTC1 and RTC0 disabled, 32 KB SRAM retained, LFXTAL off	0.69	0.81	3.0	7.1	μA
	RTC1 enabled, 8 KB SRAM retained, LFOSC as source for RTC1	0.69	0.78	2.05	6.1	μA
	RTC1 enabled, 8 KB SRAM retained, LFXTAL as source for RTC1	0.74	0.83	2.1	6.15	μA
	RTC1 and RTC0 enabled, 8 KB SRAM retained, LFXTAL as source for RTC1 and RTC0	0.83	0.93	2.25	6.3	μA
Shutdown	RTC0 enabled, LFXTAL as source for RTC0	290	310	490	1180	nA
	RTC0 disabled	40	56	260	950	nA

¹ Buck enable/disable selection does not affect power consumption.

ADuCM3027/ADuCM3029

SYSTEM CLOCKS/TIMERS

Table 7 and Table 8 show the system clock specifications for the ADuCM3027/ADuCM3029 MCUs.

Platform External Crystal Oscillator

Table 7. Platform External Crystal Oscillator Specifications

Parameter	Min	Typ	Max	Unit	Conditions
LOW FREQUENCY EXTERNAL CRYSTAL OSCILLATOR (LFX TAL) $C_{EXT1} = C_{EXT2}$	6		10	pF	External capacitor, $C_{EXT1} = C_{EXT2}$ (symmetrical load), for $C_L \leq 5$ pF (maximum) and $ESR = 30$ k Ω (maximum). C_{EXT1} , C_{EXT2} must be selected considering the printed circuit board (PCB) trace capacitance due to routing.
Frequency		32,768		Hz	
HIGH FREQUENCY EXTERNAL CRYSTAL OSCILLATOR (HFXTAL) $C_{EXT1} = C_{EXT2}$			20	pF	External capacitor, $C_{EXT1} = C_{EXT2}$ (symmetrical load), for $C_L = 10$ pF (maximum) and $ESR = 50$ Ω (maximum). C_{EXT1} , C_{EXT2} must be selected considering the PCB trace capacitance due to routing.
Frequency		26		MHz	

On-Chip RC Oscillator

Table 8. On-Chip RC Oscillator Specifications

Parameter	Min	Typ	Max	Unit	Conditions
HIGH FREQUENCY RC OSCILLATOR (HFOSC) Frequency	25.09	26	26.728	MHz	
LOW FREQUENCY RC OSCILLATOR (LFOSC) Frequency	30,800	32,768	34,407	Hz	

ADuCM3027/ADuCM3029

ABSOLUTE MAXIMUM RATINGS

Stresses at or above those listed in [Table 11](#) may cause permanent damage to the product. This is a stress rating only. The functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

Table 11. Absolute Maximum Ratings

Parameter	Rating	Unit
SUPPLY		
VBAT_ANA1	−0.3 to +3.6	V
VBAT_ANA2		
VBAT_ADC		
VBAT_DIG1		
VBAT_DIG2		
VREF_ADC		
ANALOG		
VDCDC_CAP1N	−0.3 to +3.6	V
VDCDC_AP1P		
VDCDC_OUT		
VDCDC_CAP2N		
VDCDC_CAP2P		
VLDO_OUT	−0.3 to +1.32	V
SYS_HFXTAL_IN		
SYS_HFXTAL_OUT		
SYS_LFXTAL_IN		
SYS_LFXTAL_OUT		
DIGITAL INPUT/OUTPUT		
P0.X	−0.3 to +3.6	V
P1.X		
P2.X		
SYS_HWRST		

ESD SENSITIVITY



ESD (electrostatic discharge) sensitive device.

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PACKAGE INFORMATION

[Figure 4](#) and [Table 12](#) provide details about package branding. For a complete listing of product availability, see the [Ordering Guide](#) section.



Figure 4. Product Information on Package¹

¹ Exact brand may differ, depending on package type.

Table 12. Package Brand Information

Brand Key	Field Description
ADuCM3027/ADuCM3029	Product model
t	Temperature range
pp	Package type
Z	RoHS compliant designation
ccc	See the Ordering Guide section
vvvvvv.x	Assembly lot code
n.n	Silicon revision
yyww	Date code

Table 16. Serial Ports—Internal Clock

Parameter		Min	Max	Unit
TIMING REQUIREMENTS				
t_{SDRI}	Receive Data Setup Before SPT_CLK ¹	25		ns
t_{HDRI}	Receive Data Hold After SPT_CLK ¹	0		ns
SWITCHING CHARACTERISTICS				
t_{DFSI}	Frame Sync Delay After SPT_CLK (Internally Generated Frame Sync in Transmit or Receive Mode) ²		20	ns
t_{HOFSI}	Frame Sync Hold After SPT_CLK (Internally Generated Frame Sync in Transmit or Receive Mode) ²	-8		ns
t_{DDTI}	Transmit Data Delay After SPT_CLK ²		20	ns
t_{HDTI}	Transmit Data Hold After SPT_CLK ²	-7		ns
t_{SCLKIW}	SPT_CLK Width	$t_{PCLK} - 1.5$		ns
t_{SPTCLK}	SPT_CLK Period	$2 \times t_{PCLK} - 1$		ns

¹ This specification is referenced to the sample edge.

² This specification is referenced to the drive edge.

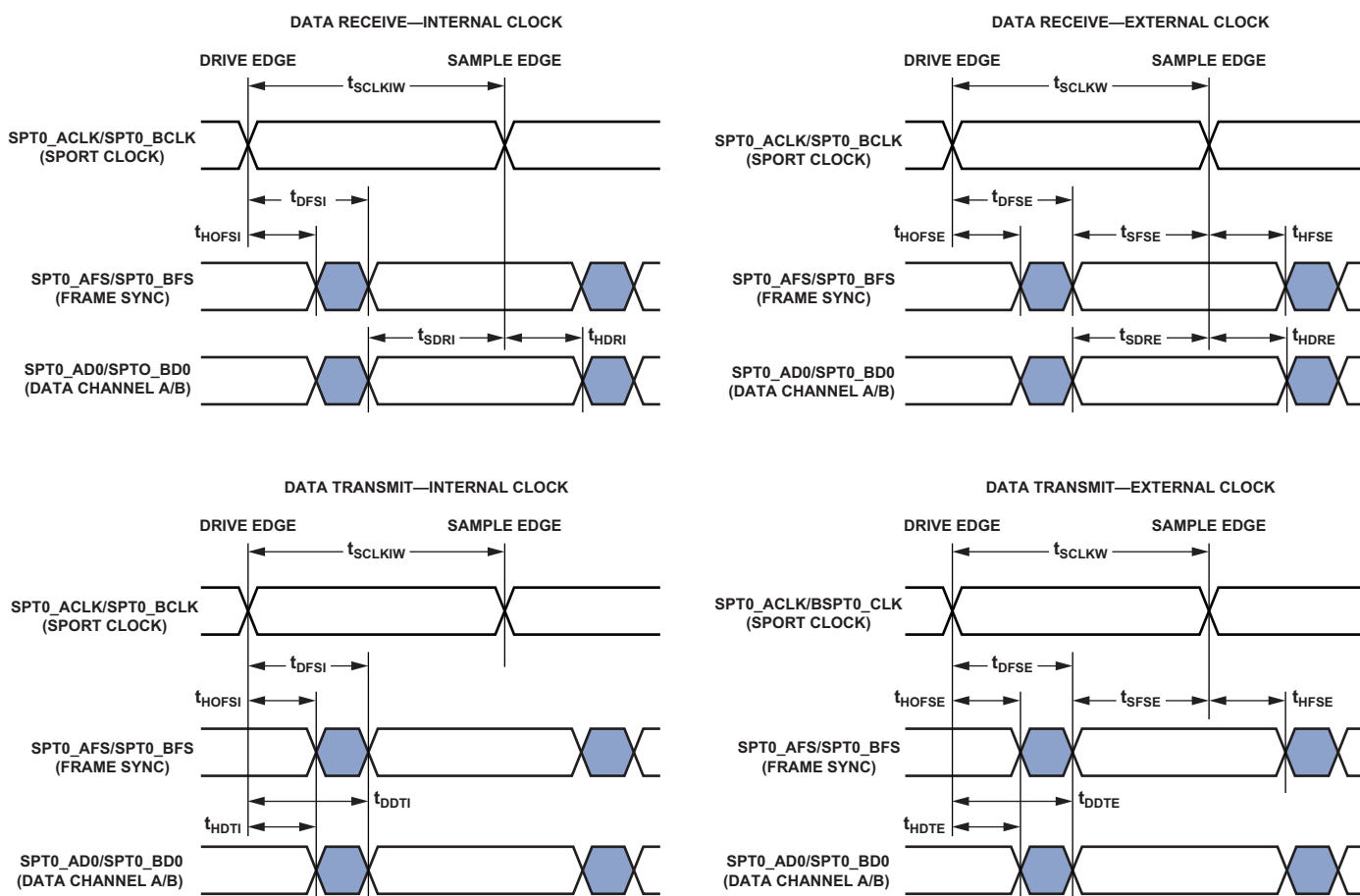


Figure 6. Serial Ports

Table 17. Serial Ports—Enable and Three-State

Parameter	Min	Max	Unit
SWITCHING CHARACTERISTICS			
t_{DDTIN} Data Enable From Internal Transmit SPT_CLK ¹	5		ns
t_{DDTTI} Data Disable From Internal Transmit SPT_CLK ¹		160	ns

¹ This specification is referenced to the drive edge.

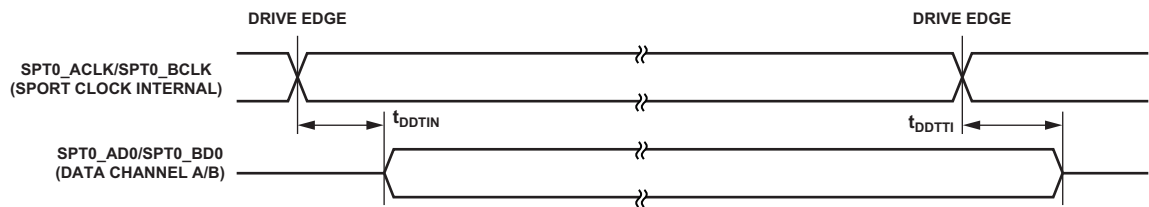


Figure 7. Serial Ports—Enable and Three-State

SPI Timing

Table 18, Figure 8, and Figure 9 (for master mode) and Table 19, Figure 10, and Figure 11 (for slave mode) describe SPI timing specifications. High speed SPI (SPIH) can be used for high data rate peripherals.

Table 18. SPI Master Mode Timing¹

Parameter		Min	Max	Unit
TIMING REQUIREMENTS				
t_{CS}	$\overline{CS}$ to SCLK Edge	$0.5 \times t_{PCLK} - 3$		ns
t_{SL}	SCLK Low Pulse Width	$t_{PCLK} - 3.5$		ns
t_{SH}	SCLK High Pulse Width	$t_{PCLK} - 3.5$		ns
t_{DSU}	Data Input Setup Time Before SCLK Edge	5		ns
t_{DHD}	Data Input Hold Time After SCLK Edge	20		ns
SWITCHING CHARACTERISTICS				
t_{DAV}	Data Output Valid After SCLK Edge		25	ns
t_{DOSU}	Data Output Setup Before SCLK Edge	$t_{PCLK} - 2.2$		ns
t_{SFS}	$\overline{CS}$ High After SCLK Edge	$0.5 \times t_{PCLK} - 3$		ns

¹This specification is characterized with respect to double drive strength.

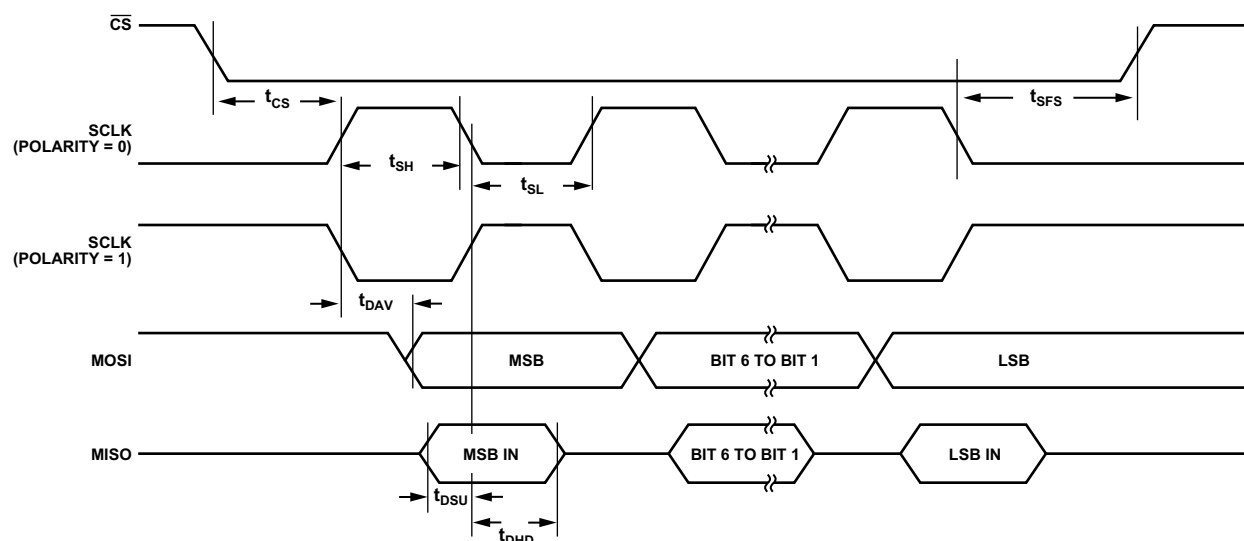


Figure 8. SPI Master Mode Timing (Phase Mode = 1)

General-Purpose Port Timing

Table 20 and Figure 12 describe general-purpose port timing.

Table 20. General-Purpose Port Timing

Parameter	Min	Max	Unit
TIMING REQUIREMENTS			
t_{WFI} General-Purpose Port Pin Input Pulse Width	$4 \times t_{PCLK}$		ns

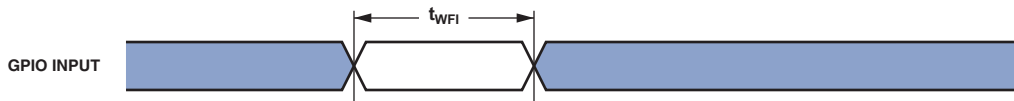


Figure 12. General-Purpose Port Timing

Timer PWM_OUT Cycle Timing

Table 21 and Figure 13 describe timer PWM_OUT cycle timing.

Table 21. Timer PWM_OUT Cycle Timing

Parameter	Min	Max	Unit
SWITCHING CHARACTERISTICS			
t_{PWM0} Timer Pulse Width Output	$4 \times t_{PCLK} - 6$	$256 \times (2^{16} - 1)$	ns

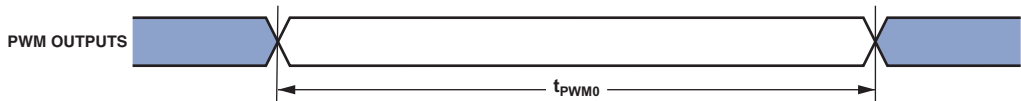


Figure 13. Timer PWM_OUT Cycle Timing

ADuCM3027/ADuCM3029

Figure 16 through Figure 21 show the typical current voltage characteristics for the output drivers of the MCU.

The curves represent the current drive capability of the output drivers as a function of output voltage.

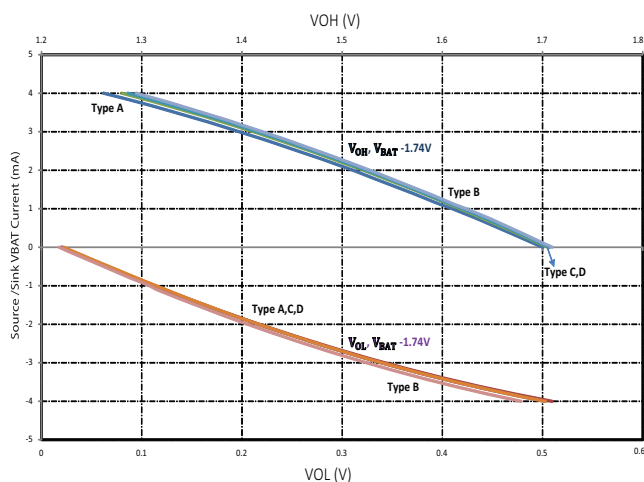


Figure 16. Output Double Drive Strength Characteristics ($V_{BAT} = 1.74\text{ V}$)

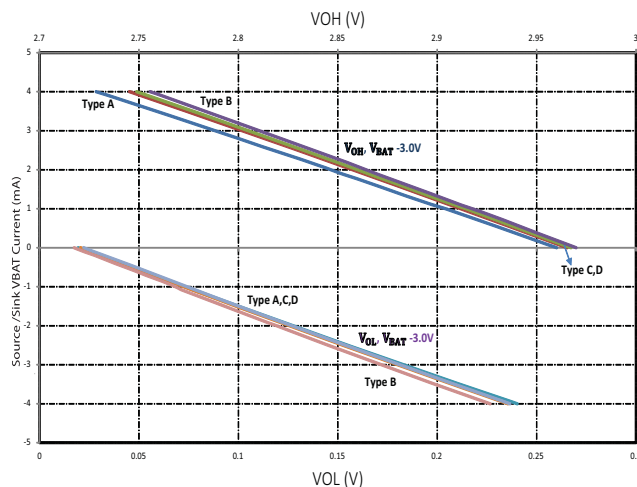


Figure 18. Output Double Drive Strength Characteristics ($V_{BAT} = 3.0\text{ V}$)

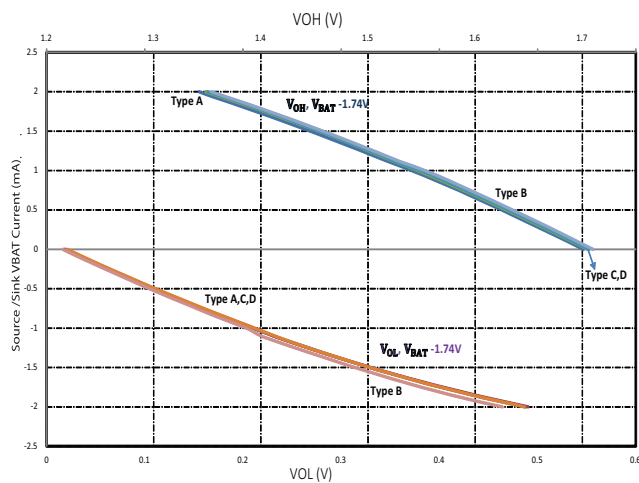


Figure 17. Output Single Drive Strength Characteristics ($V_{BAT} = 1.74\text{ V}$)

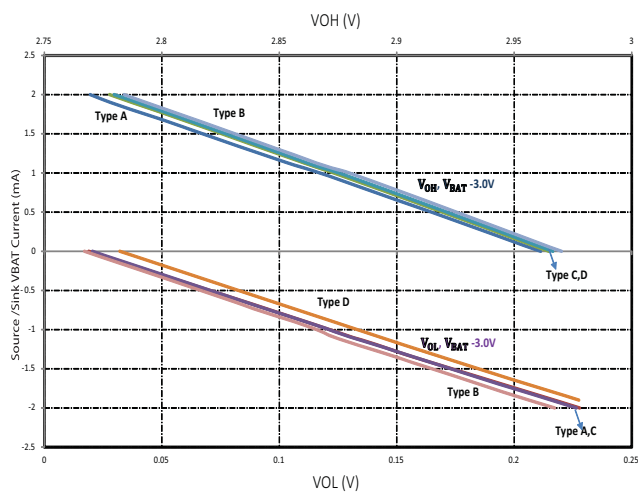


Figure 19. Output Single Drive Strength Characteristics ($V_{BAT} = 3.0\text{ V}$)

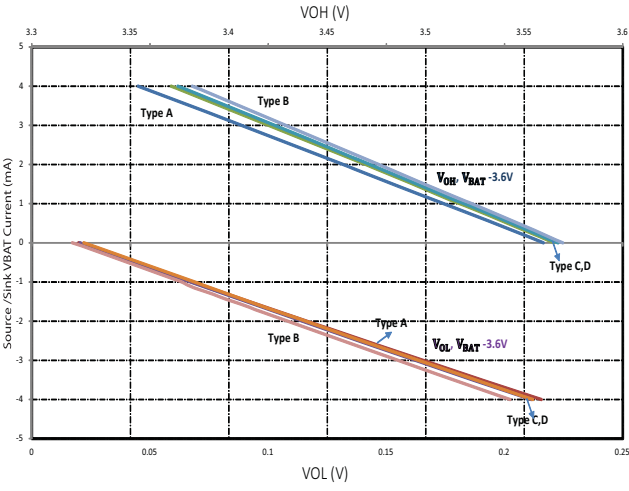


Figure 20. Output Double Drive Strength Characteristics ($V_{BAT} = 3.6\text{ V}$)

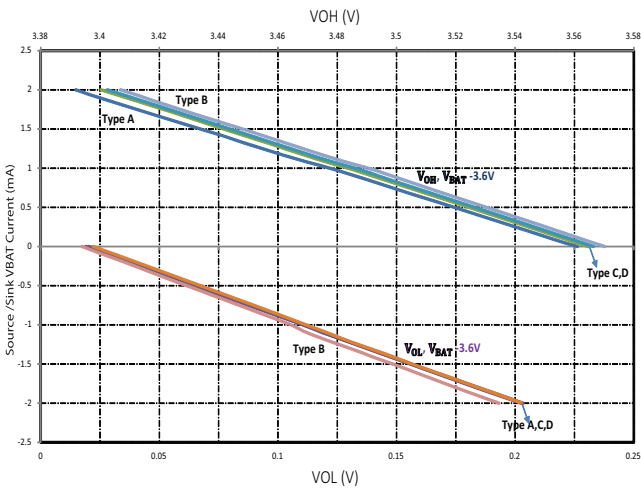


Figure 21. Output Single Drive Strength Characteristics ($V_{BAT} = 3.6\text{ V}$)

ENVIRONMENTAL CONDITIONS

Table 23. Thermal Characteristics (64-Lead LFCSP)

Parameter	Typ	Unit
θ_{JA}	28.2	$^{\circ}\text{C}/\text{W}$
θ_{JC}	5.4	$^{\circ}\text{C}/\text{W}$

Values of θ_{JA} are provided for package comparison and PCB design considerations. θ_{JA} can be used for a first-order approximation of T_J by the equation:

$$T_J = T_A + (\theta_{JA} \times P_D)$$

where:

T_A is ambient temperature ($^{\circ}\text{C}$).

T_J is junction temperature ($^{\circ}\text{C}$).

P_D is power dissipation (To calculate P_D , see the [Power Supply Current](#) section).

Values of θ_{JC} are provided for package comparison and PCB design considerations when an external heat sink is required.

PIN CONFIGURATION AND FUNCTION DESCRIPTION

Figure 22 shows an overview of signal placement on the 64-Lead LFCSP_WQ.

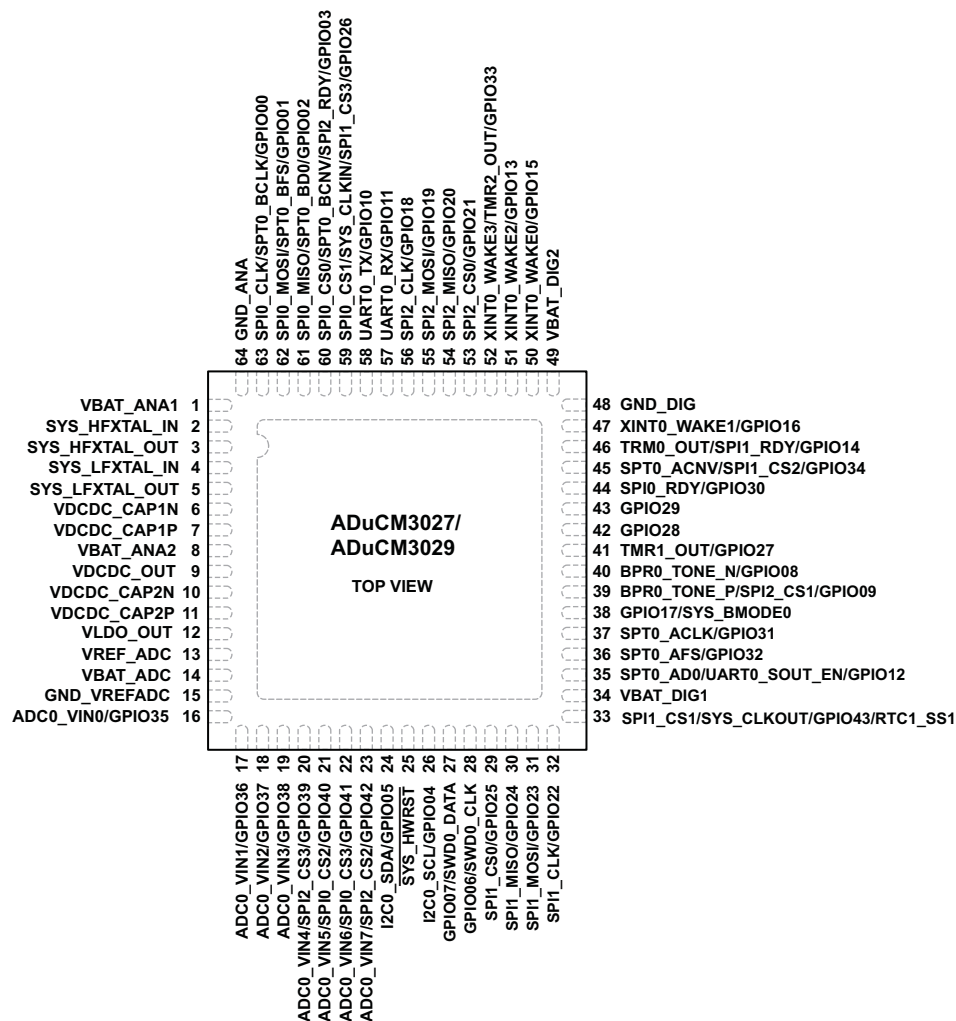


Figure 22. 64-Lead LFCSP Configuration

Table 24 lists the signal descriptions of the ADuCM3027/ADuCM3029 MCUs.

Table 24. Signal Functional Descriptions

GPIO Signal Name	Description
SPI _n _CLK	SPI Clock. n = 0, 1, 2.
SPI _n _MOSI	SPI Master Out Slave In. n = 0, 1, 2.
SPI _n _MISO	SPI Master In Slave Out. n = 0, 1, 2.
SPI _n _RDY	SPI Ready Signal. n = 0, 1, 2.
SPI _n _CS _m	SPI Chip Select Signal. n = 0, 1, 2 and m = 0, 1, 2, 3.
SPT0_ACLK	SPORT A Clock Signal.
SPT0_AFS	SPORT A Frame Sync.
SPT0_AD0	SPORT A Data Pin 0.
SPT0_ACNV	SPORT A Converter Signal for Interface with ADC.
SPT0_BCLK	SPORT B Clock Signal.
SPT0_BFS	SPORT B Frame Sync.
SPT0_BD0	SPORT B Data Pin 0.
SPT0_BCNV	SPORT B Converter Signal for Interface with ADC.
I2C0_SCL	I ² C Clock.
I2C0_SDA	I ² C Data.
SWD0_CLK	Serial Wire Debug Clock.
SWD0_DATA	Serial Wire Debug Data.
BPR0_TONE_N	Beeper Tone Negative Pin.
BPR0_TONE_P	Beeper Tone Positive Pin.
UART0_TX	UART Transmit Pin.
UART0_RX	UART Receive Pin.
UART0_SOUT_EN	UART Serial Data Out Pin.
XINT0_WAKEn	System Wake-Up Pin. Wake Up from Flexi/Hibernate/Shutdown Modes ¹ . n = 0, 1, 2, 3.
TMRn_OUT	Timer Output Pin. n = 0, 1, 2.
SYS_BMODE0	Boot Mode Pin.
SYS_CLKIN	External Clock In Pin.
SYS_CLKOUT	External Clock Out Pin.
RTC1_SS1	RTC1 SensorStrobe Pin.
ADC0_VINn	ADC Voltage Input Pin. n = 0, 1, 2, 3, 4, 5, 6, 7.

¹ For shutdown, XINT0_WAKE3 is not capable of waking the device from shutdown mode.

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Table 25 lists the 64-Lead LFCSP_WQ package by pin number for the ADuCM3027/ADuCM3029 MCUs.

Table 25. Pin Function Descriptions, 64-Lead LFCSP_WQ

Pin No.	GPIO	Signal Name	Description	GPIO Pull
1		VBAT_ANA1	Analog 3 V Supply.	
2		SYS_HFXTAL_IN	26 MHz High Frequency Crystal.	
3		SYS_HFXTAL_OUT	26 MHz High Frequency Crystal.	
4		SYS_LFXTAL_IN	32 kHz Low Frequency Crystal.	
5		SYS_LFXTAL_OUT	32 kHz Low Frequency Crystal.	
6		VDCDC_CAP1N	Buck Fly Capacitor.	
7		VDCDC_CAP1P	Buck Fly Capacitor.	
8		VBAT_ANA2	Analog 3 V Supply.	
9		VDCDC_OUT	Buck Output Capacitor.	
10		VDCDC_CAP2N	Buck Fly Capacitor.	
11		VDCDC_CAP2P	Buck Fly Capacitor.	
12		VLDO_OUT	LDO Output Capacitor.	
13		VREF_ADC	Analog Reference Voltage for ADC.	
14		VBAT_ADC	Analog 3 V Supply for ADC.	
15		GND_VREFADC	Reference Ground for ADC.	
16	P2_03	ADC0_VIN0/GPIO35		PU
17	P2_04	ADC0_VIN1/GPIO36		PU
18	P2_05	ADC0_VIN2/GPIO37		PU
19	P2_06	ADC0_VIN3/GPIO38		PU
20	P2_07	ADC0_VIN4/SPI2_CS3/GPIO39		PU
21	P2_08	ADC0_VIN5/SPI0_CS2/GPIO40		PU
22	P2_09	ADC0_VIN6/SPI0_CS3/GPIO41		PU
23	P2_10	ADC0_VIN7/SPI2_CS2/GPIO42		PU
24	P0_05	I2C0_SDA/GPIO05		PU
25		SYS_HWRST	System Hardware Reset.	
26	P0_04	I2C0_SCL/GPIO04		PU
27	P0_07	GPIO07/SWD0_DATA		PU
28	P0_06	GPIO06/SWD0_CLK		PD
29	P1_09	SPI1_CS0/GPIO25		PU
30	P1_08	SPI1_MISO/GPIO24		PU
31	P1_07	SPI1_MOSI/GPIO23		PU
32	P1_06	SPI1_CLK/GPIO22		PU
33	P2_11	SPI1_CS1/SYS_CLKOUT/GPIO43/RTC1_SS1		PU
34		VBAT_DIG1	Digital 3 V Supply.	
35	P0_12	SPT0_AD0/GPIO12		PU
36	P2_00	SPT0_AFS/GPIO32		PU
37	P1_15	SPT0_ACLK/GPIO31		PU
38	P1_01	GPIO17/SYS_BMODE0		PU
39	P0_09	BPR0_TONE_P/SPI2_CS1/GPIO09		PU
40	P0_08	BPR0_TONE_N/GPIO08		PU
41	P1_11	TMR1_OUT/GPIO27		PU
42	P1_12	GPIO28		PU
43	P1_13	GPIO29		PU
44	P1_14	SPI0_RDY/GPIO30		PU
45	P2_02	SPT0_ACNV/SPI1_CS2/GPIO34		PU

Table 26. Pin Function Descriptions, 54-Ball WLCSP (Continued)

Ball No.	GPIO	Pin Label	Description	GPIO Pull
G05	P0_13	XINT0_WAKE2/GPIO13	Digital 3 V Supply.	PU
G07	P1_01	GPIO17/SYS_BMODE0		PU
G09	P1_06	SPI1_CLK/GPIO22		PU
G11	P2_11	SPI1_CS1/SYS_CLKOUT/GPIO43/RTC1_SS1		PU
G13		VBAT_DIG1		
H02	P1_00	XINT0_WAKE1/GPIO16		PU
H04	P0_14	TMR0_OUT/SPI1_RDY/GPIO14		PU
H06	P1_14	SPI0_RDY/GPIO30		PU
H08	P0_08	BPR0_TONE_N/GPIO08		PU
H10	P0_09	BPR0_TONE_P/SPI2_CS1/GPIO09		PU
H12	P0_12	SPT0_AD0/GPIO12/UART0_SOUT_EN		PU

OUTLINE DIMENSIONS

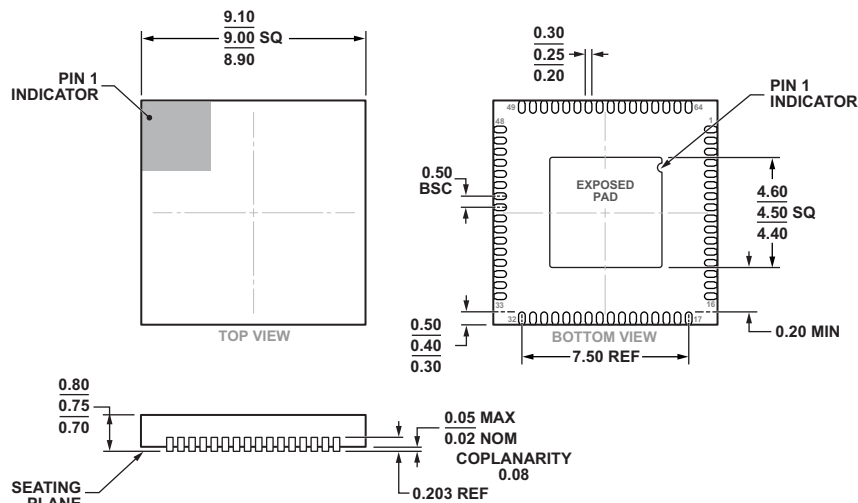


Figure 24. 64-Lead Frame Chip Scale Package [LFCSP]
9 mm x 9 mm Body and 0.75 mm Package Height
(CP-64-16)

Dimensions shown in mm

Note: Exposed pad must be grounded

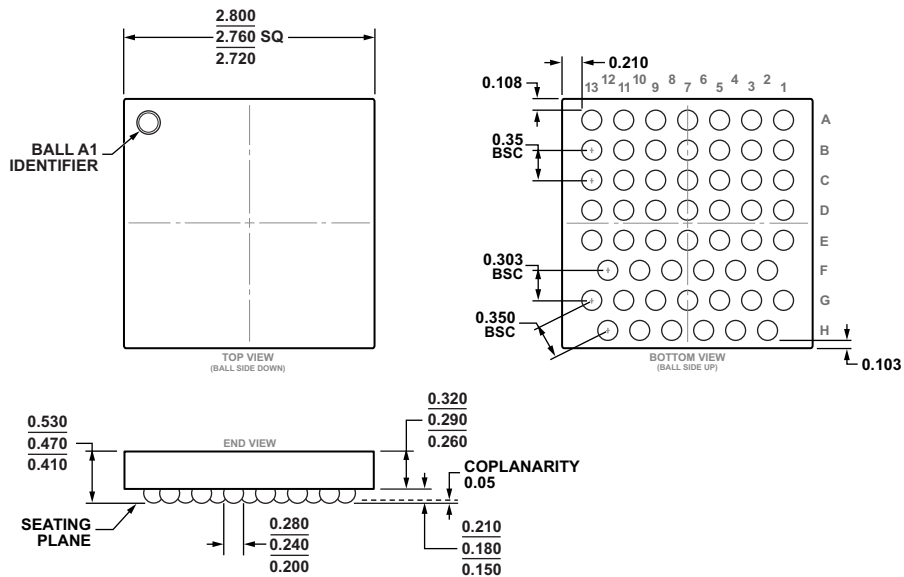


Figure 25. 54-Ball Wafer Level Chip Scale Package [WL CSP]
(CB-54-1)

Dimensions shown in mm

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ORDERING GUIDE

Model ¹	Description	Temperature ^{2, 3}	Package Description	Package Option
ADUCM3027BCBZ-RL	ULP ARM Cortex-M3 with 128 KB Embedded Flash	–40°C to +85°C	54-Ball WLCSP, 13" Reel	CB-54-1
ADUCM3027BCBZ-R7	ULP ARM Cortex-M3 with 128 KB Embedded Flash	–40°C to +85°C	54-Ball WLCSP, 7" Reel	CB-54-1
ADUCM3027BCPZ	ULP ARM Cortex-M3 with 128 KB Embedded Flash	–40°C to +85°C	64-Lead LFCSP	CP-64-16
ADUCM3027BCPZ-RL	ULP ARM Cortex-M3 with 128 KB Embedded Flash	–40°C to +85°C	64-Lead LFCSP, 13" Reel	CP-64-16
ADUCM3027BCPZ-R7	ULP ARM Cortex-M3 with 128 KB Embedded Flash	–40°C to +85°C	64-Lead LFCSP, 7" Reel	CP-64-16
ADUCM3029BCBZ-RL	ULP ARM Cortex-M3 with 256 KB Embedded Flash	–40°C to +85°C	54-Ball WLCSP, 13" Reel	CB-54-1
ADUCM3029BCBZ-R7	ULP ARM Cortex-M3 with 256 KB Embedded Flash	–40°C to +85°C	54-Ball WLCSP, 7" Reel	CB-54-1
ADUCM3029BCPZ	ULP ARM Cortex-M3 with 256 KB Embedded Flash	–40°C to +85°C	64-Lead LFCSP	CP-64-16
ADUCM3029BCPZ-RL	ULP ARM Cortex-M3 with 256 KB Embedded Flash	–40°C to +85°C	64-Lead LFCSP, 13" Reel	CP-64-16
ADUCM3029BCPZ-R7	ULP ARM Cortex-M3 with 256 KB Embedded Flash	–40°C to +85°C	64-Lead LFCSP, 7" Reel	CP-64-16
ADZS-UCM3029EZLITE	ADuCM3029 Evaluation Kit	–40°C to +85°C	64-Lead LFCSP	CP-64-16

¹ Z = RoHS Compliant Part.

² Referenced temperature is ambient temperature. The ambient temperature is not a specification. See the [Absolute Maximum Ratings](#) section for T_j (junction temperature) specification which is the only temperature specification.

³ These are preproduction devices. See ENG-Grade agreement for details.

I²C refers to a communications protocol originally developed by Philips Semiconductors (now NXP Semiconductors).